



Features

- Surface Mount SMC package
- Standoff Voltage: 12 to 58 volts
- Power Dissipation: 3000 watts
- RoHS compliant*
- AEC-Q101 compliant**

Applications

- Protection of power buses
- Protection of I/O interfaces
- Overvoltage transient protection
- Automotive
 - Entertainment applications
 - Comfort applications
- Telecom, computer, industrial and consumer electronics applications

SMLJ-Q Transient Voltage Suppressor Diode Series

General Information

Bourns offers Transient Voltage Suppressor Diodes for surge and ESD protection applications, in compact chip package DO-214AB (SMC) size format. The Transient Voltage Suppressor series offers a choice of Working Peak Reverse Voltage from 12 V up to 58 V. Typical fast response times are less than 1.0 picosecond from 0 V to Breakdown Voltage.

Bourns® Chip Diodes conform to JEDEC standards, are easy to handle with standard pick and place equipment and the flat configuration minimizes roll away.

Electrical Characteristics (@ $T_A = 25\text{ }^\circ\text{C}$ Unless Otherwise Noted)

Parameter	Symbol	Value	Unit
Minimum Peak Pulse Power Dissipation ($T_P = 1\text{ ms}$) (Note 1,2)	P_{PK}	3000	Watts
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method) (Note 3)	I_{FSM}	300	Amps
Operating Temperature Range	T_J	-55 to +150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150	$^\circ\text{C}$

1. Non-repetitive current pulse, per Pulse Waveform graph and derated above $T_A = 25\text{ }^\circ\text{C}$ per Pulse Derating Curve.
2. Mounted on 5.0 mm^2 (0.03 mm thick) copper pads to each terminal.
3. 8.3 ms Single Sine Wave duty cycle = 4 pulses maximum per minute (unidirectional units only).

BOURNS®

Asia-Pacific: Tel: +886-2 2562-4117 • Email: asiacus@bourns.com

EMEA: Tel: +36 88 520 390 • Email: eurocus@bourns.com

The Americas: Tel: +1-951 781-5500 • Email: americus@bourns.com

www.bourns.com

*RoHS Directive 2002/95/EC Jan. 27, 2003 including annex and RoHS Recast 2011/65/EU June 8, 2011.

**"Q" part number suffix indicates AEC-Q101 compliance.

Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.

SMLJ-Q Transient Voltage Suppressor Diode Series

BOURNS®

Electrical Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

Unidirectional Device		Bidirectional Device		Breakdown Voltage V _{BR} (Volts)			Working Peak Reverse Voltage	Maximum Reverse Leakage @ V _{RWM}	Maximum Reverse Voltage @ I _{RSM}	Maximum Reverse Surge Current
Part Number	Part Marking	Part Number	Part Marking	Min.	Max.	@ I _T (mA)	V _{RWM} (Volts)	I _R (μA)	V _{RSM} (Volts)	I _{RSM} (Amps)
SMLJ12A-Q	HEEQ	SMLJ12CA-Q	IEEQ	13.3	14.7	1	12	2	19.9	150.60
SMLJ13A-Q	HEGQ	SMLJ13CA-Q	IEGQ	14.4	15.9	1	13	2	21.5	139.40
SMLJ14A-Q	HEKQ	SMLJ14CA-Q	IEKQ	15.6	17.2	1	14	2	23.2	129.40
SMLJ15A-Q	HEMQ	SMLJ15CA-Q	IEMQ	16.7	18.5	1	15	2	24.4	123.00
SMLJ16A-Q	HEPQ	SMLJ16CA-Q	IEPQ	17.8	19.7	1	16	2	26.0	115.40
SMLJ17A-Q	HERQ	SMLJ17CA-Q	IERQ	18.9	20.9	1	17	2	27.6	106.60
SMLJ18A-Q	HETQ	SMLJ18CA-Q	IETQ	20.0	22.1	1	18	2	29.2	102.80
SMLJ20A-Q	HEVQ	SMLJ20CA-Q	IEVQ	22.2	24.5	1	20	2	32.4	92.60
SMLJ22A-Q	HEXQ	SMLJ22CA-Q	IEXQ	24.4	26.9	1	22	2	35.5	84.40
SMLJ24A-Q	HEZQ	SMLJ24CA-Q	IEZQ	26.7	29.5	1	24	2	38.9	77.20
SMLJ26A-Q	HFEQ	SMLJ26CA-Q	IFEQ	28.9	31.9	1	26	2	42.1	71.20
SMLJ28A-Q	HFGQ	SMLJ28CA-Q	IFGQ	31.1	34.4	1	28	2	45.4	66.00
SMLJ30A-Q	HFQK	SMLJ30CA-Q	IFKQ	33.3	36.8	1	30	2	48.4	62.00
SMLJ33A-Q	HFMQ	SMLJ33CA-Q	IFMQ	36.7	40.6	1	33	2	53.3	56.20
SMLJ36A-Q	HFPQ	SMLJ36CA-Q	IFPQ	40.0	44.2	1	36	2	58.1	51.60
SMLJ40A-Q	HFRQ	SMLJ40CA-Q	IFRQ	44.4	49.1	1	40	2	64.5	46.40
SMLJ43A-Q	HFTQ	SMLJ43CA-Q	IFTQ	47.8	52.8	1	43	2	69.4	43.20
SMLJ45A-Q	HFVQ	SMLJ45CA-Q	IFVQ	50.0	55.3	1	45	2	72.7	41.20
SMLJ48A-Q	HFXQ	SMLJ48CA-Q	IFXQ	53.3	58.9	1	48	2	77.4	38.80
SMLJ51A-Q	HFZQ	SMLJ51CA-Q	IFZQ	56.7	62.7	1	51	2	82.4	36.40
SMLJ54A-Q	HGEQ	SMLJ54CA-Q	IGEQ	60.0	66.3	1	54	2	87.1	34.40
SMLJ58A-Q	HGGQ	SMLJ58CA-Q	IGGQ	64.4	71.2	1	58	2	93.6	32.00

Notes:

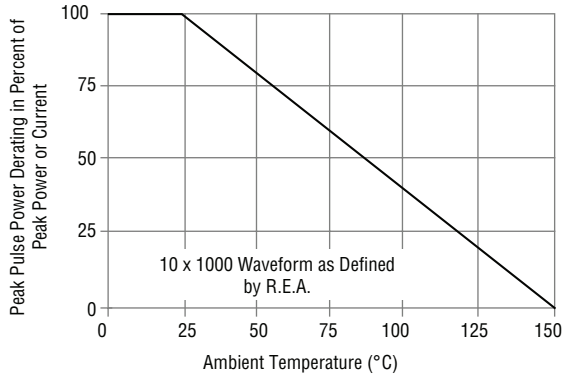
1. Suffix 'A' denotes a 5 % tolerance unidirectional device.
2. Suffix 'CA' denotes a 5 % tolerance bidirectional device.

SMLJ-Q Transient Voltage Suppressor Diode Series

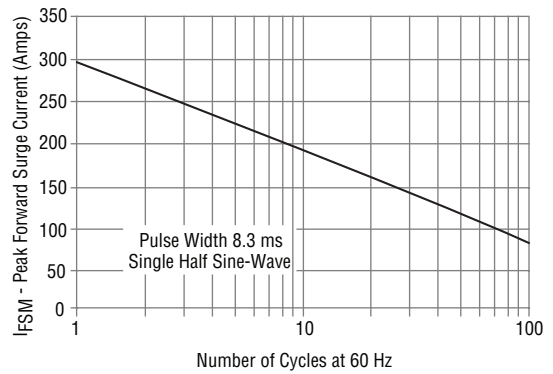


Performance Graphs

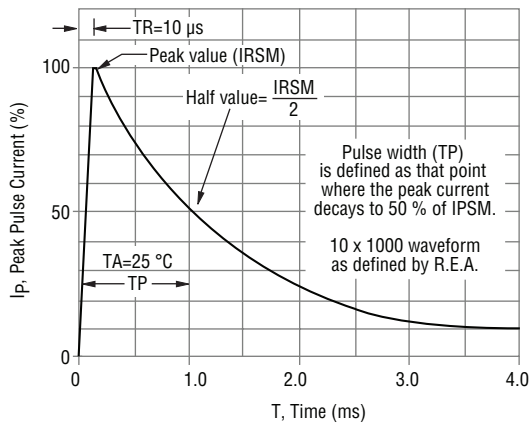
Peak Pulse Power Derating Curve



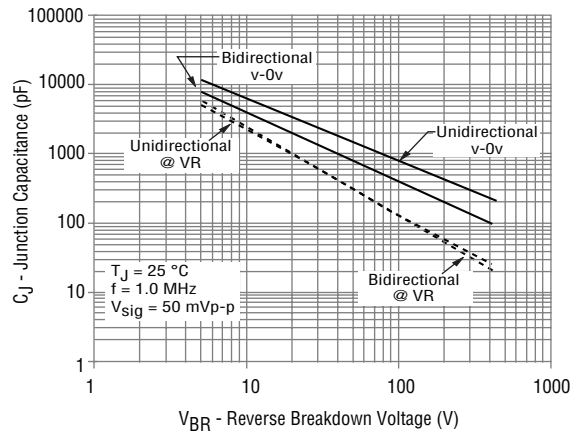
Maximum Non-Repetitive Surge Current



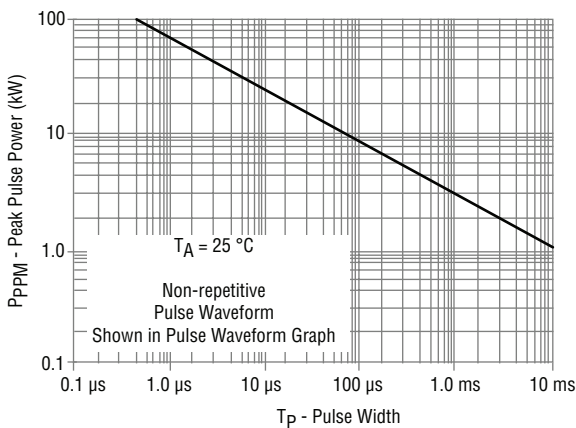
Pulse Waveform



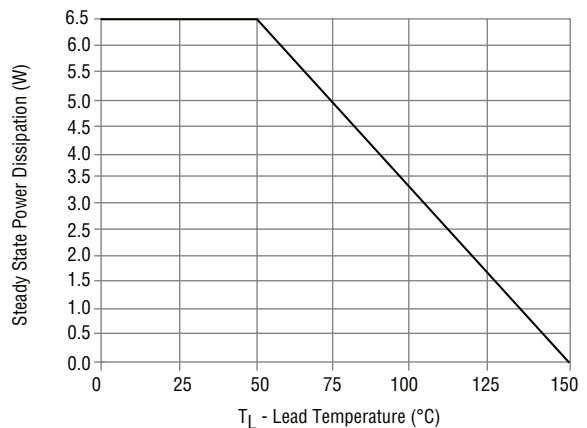
Typical Junction Capacitance



Pulse Rating Curve



Steady State Power Derating Curve



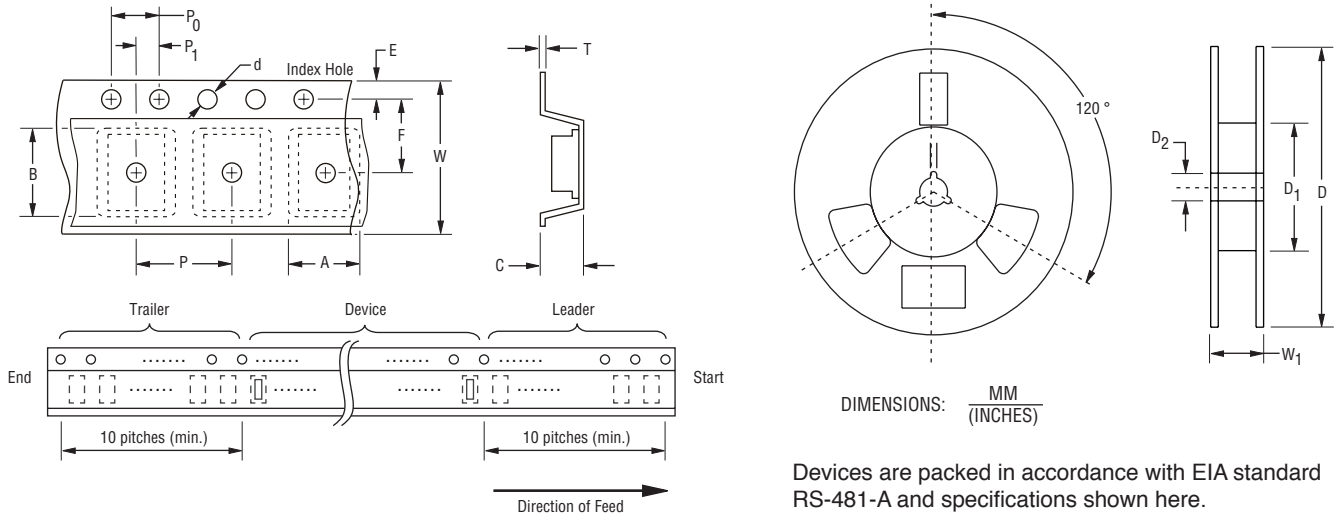
Specifications are subject to change without notice.
The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time.
Users should verify actual device performance in their specific applications.

SMLJ-Q Transient Voltage Suppressor Diode Series

BOURNS®

Packaging Information

The product will be dispensed in tape and reel format (see diagram below).



Item	Symbol	SMC (DO-214AB)	
		7-Inch Reel	13-Inch Reel
Carrier Width	A	6.0 ± 2.0 (0.236 - 0.079)	
Carrier Length	B	8.3 ± 0.20 (0.327 ± 0.008)	
Carrier Depth	C	2.5 ± 0.20 (0.098 ± 0.008)	
Sprocket Hole	d	1.50 ± 0.10 (0.059 ± 0.004)	
Reel Outside Diameter	D	$\frac{178}{(7.008)}$	$\frac{330}{(12.992)}$
Reel Inner Diameter	D ₁	$\frac{50.0}{(1.969)}$ MIN.	
Feed Hole Diameter	D ₂	$\frac{13.0 + 0.50 / - 0.20}{(0.512 + 0.020 / - 0.008)}$	
Sprocket Hole Position	E	1.75 ± 0.10 (0.069 ± 0.004)	
Punch Hole Position	F	7.50 ± 0.10 (0.295 ± 0.004)	
Punch Hole Pitch	P	8.00 ± 0.10 (0.315 ± 0.004)	
Sprocket Hole Pitch	P ₀	4.00 ± 0.10 (0.157 ± 0.004)	
Embossment Center	P ₁	2.00 ± 0.10 (0.079 ± 0.004)	
Overall Tape Thickness	T	0.30 ± 0.10 (0.012 ± 0.004)	
Tape Width	W	16.00 ± 0.30 (0.630 ± 0.012)	
Reel Width	W ₁	$\frac{22.4}{(0.882)}$ MAX.	
Quantity per Reel	--	500	3000

REV. 02/18

Specifications are subject to change without notice.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.